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Fine ceramics (advanced ceramics, advanced technical ceramics) — Measurement method of piezoelectric strain at high electric field

Céramiques techniques — Méthode de mesurage de la contrainte piézoélectrique à champ électrique élevé **iTeh STANDARD PREVIEW**

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Foreword

ISO (the International Organization for Standardization) is a worldwide federation of national standards bodies (ISO member bodies). The work of preparing International Standards is normally carried out through ISO technical committees. Each member body interested in a subject for which a technical committee has been established has the right to be represented on that committee. International organizations, governmental and non-governmental, in liaison with ISO, also take part in the work. ISO collaborates closely with the International Electrotechnical Commission (IEC) on all matters of electrotechnical standardization.

The procedures used to develop this document and those intended for its further maintenance are described in the ISO/IEC Directives, Part 1. In particular the different approval criteria needed for the different types of ISO documents should be noted. This document was drafted in accordance with the editorial rules of the ISO/IEC Directives, Part 2 (see www.iso.org/directives).

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For an explanation on the meaning of ISO specific terms and expressions related to conformity assessment, as well as information about ASO's adherence to the WTO principles in the Technical Barriers to Trade (TBT) see the following URL: Foreword - Supplementary information

The committee responsible for this document is ISO/TC 206, *Fine ceramics*.

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Fine ceramics (advanced ceramics, advanced technical ceramics) — Measurement method of piezoelectric strain at high electric field

1 Scope

This International Standard specifies the measurement method of piezoelectric strain at high electric field for high power piezoelectric devices. This International Standard is intended to be used to determine the piezoelectric strain coefficient of the materials by measuring strain vs. electric field:

- applied electric field: 0 to 2 MV/m;
- frequency of electric field: 0,1 to 1 Hz.

2 Normative references

The following documents, in whole or in part, are normatively referenced in this document and are indispensable for its application. For dated references, only the edition cited applies. For undated references, the latest edition of the referenced document (including any amendments) applies.

II ER SIANDARD FREVIEW IEC 60122-1, Quartz crystal units of assessed quality – Part 1: Generic specification (standards.iteh.al)

IEC 60483, Guide to dynamic measurements of piezoelectric ceramics with high electromechanical coupling

EN 50324-1, Piezoelectric properties of ceramic materials and components — Part 1: Terms and definitions https://standards.iteh.avcatalog/standards/sist/7d9fi654-5aab-4106-99e0-

EN 50324-2, Piezoelectric properties 30^f ceramic¹ materials and components — Part 2: Method of measurement — Low power

3 Terms and definitions, and symbols

3.1 Terms and definitions

For the purposes of this document, the terms and definitions given in IEC 60122-1, IEC 60483, EN 50324-1, EN 50324-2 and the following apply.

3.1.1

applied wave form

shape of voltage applied to specimen as a function of time

Note 1 to entry: Triangular waves are used in this International Standard.

3.1.2

signal generator

apparatus which controls the applied wave form

3.1.3

power source

high-voltage amplifier which generates an electric-field (E-field) applied to the specimen

3.1.4

E-field induced strain

strain of the specimen which is induced by applying the E-field

Note 1 to entry: The value is given by the ratio of displacement to specimen thickness.

3.1.5

displacement meter

apparatus which measures the E-field induced strain

3.1.6

mobile contact

mobile electrode which simultaneously holds the specimen and applies voltage to the specimen

3.1.7

maximum E-field *E*_{max}

maximum value of applied E-field

3.1.8

maximum strain

S_{max} strain at maximum E-field

3.1.9

residual strain

S_r

strain when E-field is removed

3.1.10

strain vs. E-field curve continuously plotted curve of strain as a function of E-field ist/7d9ff654-5aab-4106-99e0d7633bf4cf45/iso-17859-2015

3.2 Symbols

f	frequency
d _{max}	$= S_{\max}/E_{\max}$
E _h	electric field at which the strain difference between the up- and down-curves shows a maximum
S _h	strain difference between the up- and down-curves at E_h
H _{max}	$= S_{\rm h}/S_{\rm max}$

4 Measuring environment

The measurement should be carried out in an environment free from acoustic noise and vibrations. It is desirable to control the measurement temperature 25 ± 5 °C and relative humidity less than 60 %.

5 Specimens

5.1 General

The test specimen shall be of any ceramics that can be cut into desired shapes such as disks and quadrilateral plates. There is no limit in specimen size and shape, if the specimen is held horizontally with a small tilt.

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5.2 Shape and size

Specimens are made by cutting out from ceramics or single crystals. The shape of the specimen should be disk or quadrilateral plate, with smooth surfaces. Thickness distribution less than ± 1 % is desirable within the plate. The standard dimensions of the specimen are 0,3 mm - 1,0 mm in thickness, 5 mm - 15 mm in size, and 15 - 25 in the ratio of size to thickness. A desirable example of such disc is 0,5 mm in thickness and 10 mm in diameter.

5.3 Electrodes

Electrodes should be deposited on both sides of the specimen plate, leaving the edge region free. This edge region should have an area of less than 10 % of the sample surface. The electrode is desirable with tough adhesion and without deterioration. An example of such electrode metal is Au, Ag and Pt.

5.4 Polarization

The specimen should be treated by a poling procedure. Polarized direction should be shown on the specimen surface. Typically the positive side of the sample is marked with a dot or cross.

6 Principle

The strain of the specimen is induced by the piezoelectric effect when an electric field is applied between the two electrodes of the specimen. The strain is detected as the thickness variation of the specimen using a displacement meter. The strain vs DE-field curve is drawn, and the piezoelectric constant is calculated from this curve.

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7 Measurement equipment

<u>ISO 17859:2015</u>

7.1 Equipment https://standards.iteh.ai/catalog/standards/sist/7d9ff654-5aab-4106-99e0d7633bf4cf45/iso-17859-2015

Figure 1 shows an example of a system block diagram for piezoelectric strain measurement.



Key

- 1 signal generator
- 2 power source
- 3 displacement meter
- 4 displacement sensor
- 5 monitor
- 6 specimen

Figure 1 — Schematic diagram of piezoelectric strain measurement

7.2 Components of equipment

7.2.1 Signal generator. A function generator is recommended to generate the triangular waveform with the frequency range of 0,1 Hz to 1 Hz. <u>Figure 2</u> shows an example of an applied waveform.

7.2.2 Power source. A power source which can generate voltages as high as several kV should be used.

7.2.3 Displacement meter. A measuring accuracy of \pm 10 nm is needed for the displacement sensor. Both contact and non-contact sensors can be used. Different kinds of measuring system which have the required measuring accuracy can be used, such as differential inductive displacement gauge, magneto-resistance type linear displacement sensor, laser interferometer, capacitive method, etc.

7.2.4 Monitor. Instruments such as analog-to-digital converters and oscilloscopes are used for monitoring the relation between applied E-field and displacement, and for data acquisition.



Figure 2 — Example of applied wave form

7.2.5 Specimen holder. The specimen can be held horizontally or vertically. The specimen is placed between a stationary contact and a moving contact. The tip of the moving contact is recommended to have a sphere shape with a radius less than 2 mm. The tip of the stationary contact should be flat with a diameter less than 30 % of specimen diameter. The mechanical stress to the specimen shall be kept as low as possible in the measurement. The specimen holder has a structure which stably holds the specimen under applied E-field between both electrodes of the specimen. Figure 3 shows an example of specimen holder structure. The bottom of the stationary contact is fixed in a metal base which is connected to the ground. The moving contact is supported by a linear bearing, which is fixed in a polymer block and is connected by a wire to the power source.

Key X

Y

time (s)

E(MV/m)



Кеу

- 1 specimen
- 2 stationary contact
- 3 metal stand
- 4 moving contact
- 5 linear bearing
- 6 polymer block
- 7 wire to power source Teh STANDARD PREVIEW

Figure 85 Example of specimen holder structure

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7.3 Environment of specimen holder tradads/sist/7d9ff654-5aab-4106-99e0-

d7633bf4cf45/iso-17859-2015 The specimen holder should be placed on an anti-vibration stage. A cover of the specimen holder is recommended to remove acoustic noise and to maintain a constant specimen temperature. It is effective to prevent discharge by immersing the specimen in isolation oil, although the use of isolation oil is not mandatory.

7.4 Calibration of measurement equipment

The measurement system shall be calibrated by using a reference sample (see Annex A for an example), which is accompanied by measured S_{max} data using the calibrated equipment. Measurement conditions and procedures for the reference sample are specified in <u>Clause 8</u> and <u>Clause 9</u>, respectively. It is desirable that the measured strain at 1 MV/m is within the permissible range of the reference sample. If the measured value is out of range, it is recommended firstly to confirm movement of the mobile contact. If the mobile contact moves normally, then it is recommended to carry out calibration of signal generator, power source and displacement meter.

8 Measurement conditions

Strain vs. E-field curves are measured with unipolar change of E-field: the direction of the E-field should be parallel to the specimen poling direction. Triangular wave excitation should be used for the measurement. One cycle is defined by a ramp from 0 MV/m to the maximum E-field, the up-curve, followed by a ramp down to 0 MV/m, the down-curve, continuously. The frequency of the E-field is defined as the inverse time of one cycle. The time interval between each cycle can be chosen arbitrarily. The maximum E-field is less than 2 MV/m.

9 Measurement procedures